

RoHS

COMPLIANT HALOGEN

FREE Available

Vishay Siliconix

N-Channel 250-V (D-S) MOSFET

PRODUCT SUMMARY				
V _{DS} (V)	R_{DS(on)} (Ω)	I _D (A)		
250	0.435 at V _{GS} = 10 V	1.95		
	0.445 at V _{GS} = 6 V	1.9		

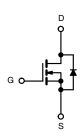
PowerPAK® 1212-8

FEATURES

- Halogen-free According to IEC 61249-2-21
 Available
- PWM-Optimized TrenchFET[®] Power MOSFET
- Avalanche Tested
- 100 % R_q Tested

APPLICATIONS

- Primary Side Switch
- Small DC/DC Circuits
- Single-Ended Primary Switching Circuits



N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS	T _A = 25 °C, unles	ss otherwise n	oted		
Parameter		Symbol	10 s	Steady State	Unit
Drain-Source Voltage		V _{DS}	250		V
Gate-Source Voltage		V _{GS}	± 20		
	T _A = 25 °C	– I _D	1.95	1.24	
Continuous Drain Current $(T_J = 150 \ ^{\circ}C)^a$	T _A = 70 °C		1.56	0.99	
Pulsed Drain Current		I _{DM}	8		А
Continuous Source Current (Diode Conduction) ^a		۱ _S	3.2	1.3	
Single Avalanche Current	L = 0.1 mH	I _{AS}	2.5		
Single Avalanche Energy		E _{AS} 0.3		mJ	
Maximum Power Dissipation ^a	T _A = 25 °C	– P _D	3.8	1.5	W
	T _A = 70 °C		2.0	0.8	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150		°C
Soldering Recommendations (Peak Temperature) ^{b, c}			260		

THERMAL RESISTANCE RATINGS						
Parameter		Symbol	Typical	Maximum	Unit	
Maximum hunding to Anthiand	t ≤ 10 s	R _{thJA}	26	33		
Maximum Junction-to-Ambient ^a	Steady State		65	81	°C/W	
Maximum Junction-to-Case (Drain)	Steady State		1.9	2.4		

Notes:

a. Surface Mounted on 1" x 1" FR4 board.

b. See Solder Profile (<u>www.vishay.com/ppg?73257</u>). The PowerPAK 1212-8 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.

c. Rework Conditions: manual soldering with a soldering iron is not recommended for leadless components.

Ordering Information: Si7802DN-T1-E3 (Lead (Pb)-free) Si7802DN-T1-GE3 (Lead (Pb)-free and Halogen-free)



Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static							
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = 250 \ \mu A$	2.4		3.6	V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 20 V$			± 100	nA	
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = 250 \text{ V}, V_{GS} = 0 \text{ V}$	1		1		
		V_{DS} = 250 V, V_{GS} = 0 V, T_{J} = 55 °C			5	μA	
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 5 \text{ V}, V_{GS} = 10 \text{ V}$	8			Α	
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = 10 V, I _D = 1.95 A		0.360	0.435	Ω	
		V _{GS} = 6 V, I _D = 1.9 A		0.370	0.445		
Forward Transconductance ^a	9 _{fs}	$V_{DS} = 15 \text{ V}, \text{ I}_{D} = 1.95 \text{ A}$		8		S	
Diode Forward Voltage ^a	V _{SD}	$I_{\rm S} = 3.2$ A, $V_{\rm GS} = 0$ V		0.8	1.2	V	
Dynamic ^b							
Total Gate Charge	Qg			14	21	nC	
Gate-Source Charge	Q _{gs}	V_{DS} = 125 V, V_{GS} = 10 V, I_{D} = 1.95 A		2.8			
Gate-Drain Charge	Q _{gd}			4.4		1	
Gate Resistance	Rg	f = 1MHz	1.6		2.4	Ω	
Turn-On Delay Time	t _{d(on)}			10	15		
Rise Time	t _r	V_{DD} = 125 V, R_L = 1.25 Ω		10	15	ns	
Turn-Off Delay Time	t _{d(off)}	$\text{I}_\text{D}\cong$ 1 A, V_GEN = 10 V, R_g = 6 Ω		21	35		
Fall Time	t _f			12	20		
Source-Drain Reverse Recovery Time	t _{rr}	I _F = 3.2 A, dl/dt = 100 A/μs		65	100		

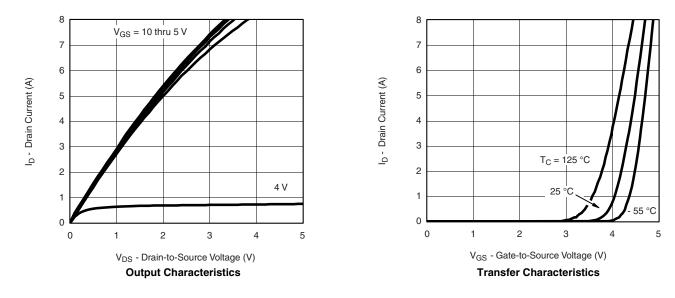
Notes:

a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

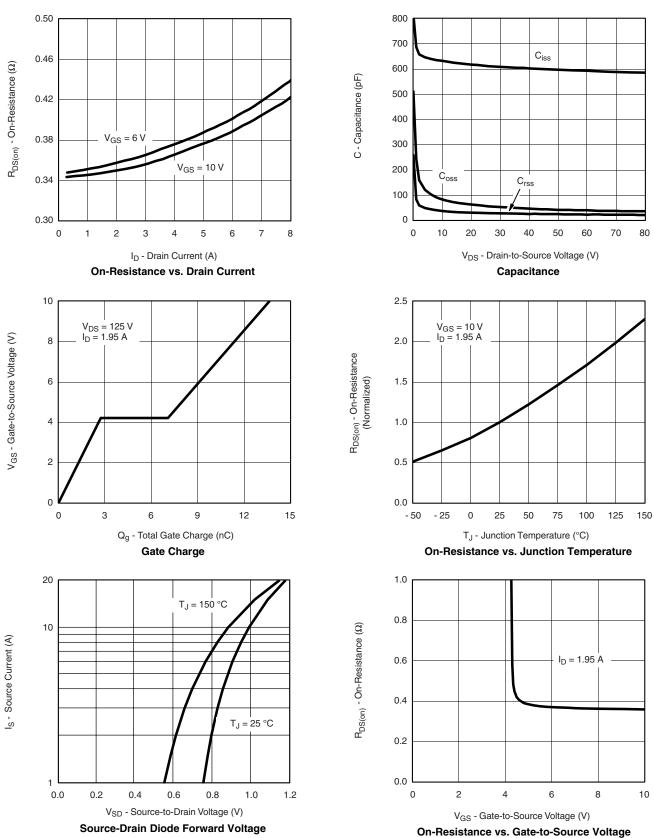
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted





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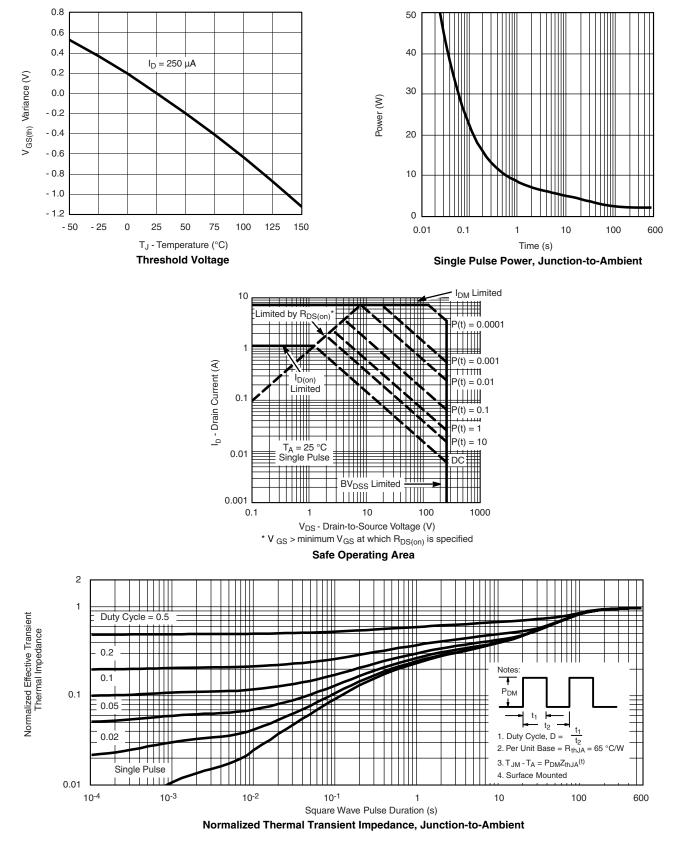


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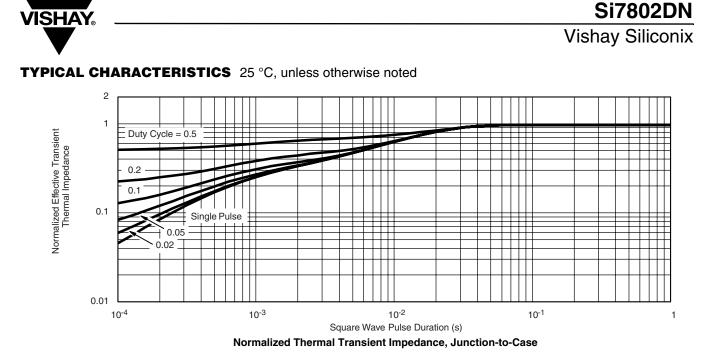
Si7802DN

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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted







Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see <u>www.vishay.com/ppg273133</u>.



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